



# Achieving Latency and Reliability Targets with QLC in Enterprise Controllers

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## Outline



- Background
  - 3D NAND flash properties and challenges
  - Why is 3D QLC NAND flash so challenging?
- Mitigation techniques and strategies in a QLC controller
  - Data placement
  - Block calibration
  - Hybrid controller architecture
  - Read heat separation
- Conclusion





## Background on 3D NAND Flash characteristics



- With increasing number of bits stored per cell, read, program, and erase latencies have been increasing in 3D NAND flash devices
- The manufacturer specified endurance for QLC flash has dropped to a level where traditional flash management technologies are not sufficient for enterprise storage applications
- Significant cost reductions with more bits per cell

Operation	Flash cell technology								
	SLC	MLC	TLC	QLC					
Page read	20 – 25 µs	55 – 110 μs	75 – 170 µs	120 – 200 µs					
Page program	50 – 100 μs	0.4 – 1.5 ms	0.8 – 2 ms	2 – 3 ms					
Block erase	2 – 5 ms	5 – 10 ms	10 – 15 ms	15 – 20 ms					
Endurance	100'000	15'000	3'000 – 5'000	800 – 1'500					
Cost per bit	_	+	++	+++					
Density	1 – 256 Gb	16Gb – 2Tb	128Gb – 8Tb	1 – 16Tb					

Source: [1] Understanding the design trade-offs of hybrid flash controllers R. Stoica, R. Pletka, N. Ioannou, N. Papandreou, S. Tomic, H. Pozidis, MASCOTS 2019



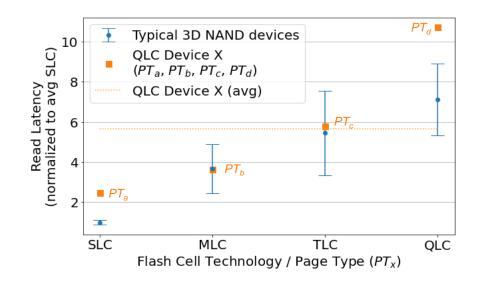


## 3D NAND Flash read latency characteristics



#### Read latency characteristics:

- Read latency varies as a function of the page type [2]
- Number of threshold voltage distributions increases exponentially with the number of bits stored per cell
- More read voltage levels must be tested upon a read operation affecting read latency



[2] P. Breen, N. Papandrou, G. Tressler, Component-Level Characterization of 3D TCL, QLC, and Low –Latency NAND, Flash Memory Summit 2019



## Overview of mitigation techniques for QLC controllers

QLC challenges	Mitigation techniques
Erase latency increase	Erase suspend
Program latency increase	Program suspend
Read latency increase	<ul> <li>SLC cache/tier</li> <li>Physical data layout (Page straddling)</li> <li>Continuous background calibration of read voltage levels</li> <li>Read heat separation</li> <li>Compression</li> </ul>
Endurance limitations	<ul> <li>Background calibration of read voltage levels</li> <li>Write heat separation [4]</li> <li>Hybrid controller architecture:         <ul> <li>Operate blocks in either a high-density multi-bit mode (e.g., QLC) or in a high-performance SLC mode</li> <li>dynamic SLC and QLC pools</li> <li>workload-optimized data placement</li> </ul> </li> <li>Wear leveling such as Health binning [5] within and between SLC and QLC tiers</li> <li>Compression</li> </ul>

<sup>[4]</sup> R. Pletka, I. Koltsidas, N. Ioannou, S. Tomić, N. Papandreou, T. Parnell, H. Pozidis, A. Fry, T. Fisher, "Management of next-generation NAND flash to achieve enterprise-level endurance and latency targets", ACM Trans. Storage, vol. 14, no. 4, Dec. 2018

<sup>[5]</sup> R. Pletka, S. Tomic, "Health-Binning: Maximizing the Performance and the Endurance of consumer-level NAND flash", SYSTOR 2016



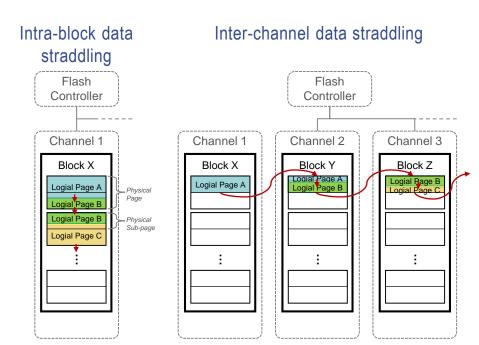


## Page straddling

## 101 01110000 01110101 011101

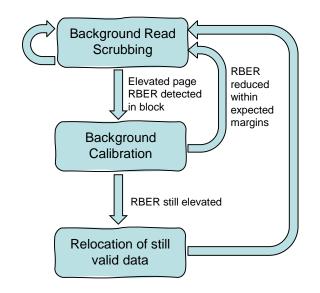
#### Intra-block vs. inter-channel data straddling

- Replace page read operation by sub-page reads on multiple channels executed concurrently
- Controller design considerations w.r.t the data layout:
  - Blocks on different channels must be organized into stripes
  - L2P mapping can be implicit for straddling logical pages.
  - Also works for compressed logical pages





- Block calibration determines optimal read voltage levels continuously in the background
  - Calibration frequency is a function of:
    - Program-erase cycles of the block,
    - Number of reads the block has seen,
    - · Retention time,
    - Page type, ...
- Benefits:
  - Significant increase in endurance
  - Significant reduction of read retry operations
  - Due to the RBER reduction, ECC using hard-decision only can be used. As no soft-information is needed, read latency is reduced
  - Does not impact host read operations





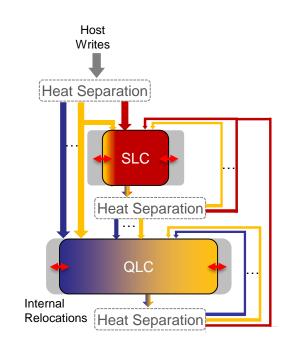


## Hybrid controller architecture for QLC Flash



#### Hybrid QLC controller design goals:

- Operate blocks in either a high-density multi-bit mode (e.g., QLC) or in a high-performance SLC mode
- Blocks can be moved between pools to adapt to workload changes (pool resizing) or for wear leveling purposes
- Data placement is done based on workload properties
  - Write heat separation: The co-location of data with similar update frequencies in the same block reduces internal write amplification [4]
  - Read heat separation re-arranges data in QLC blocks such that frequently read data is placed on faster pages (e.g., requiring fewer read thresholds to be tested)
  - Direct data placement to QLC avoids data being first written to SLC and later destaged to QLC





## Benefits from a hybrid controller architecture

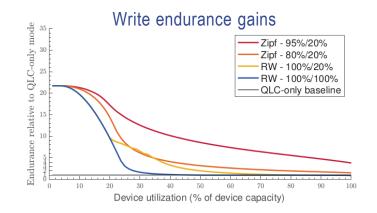


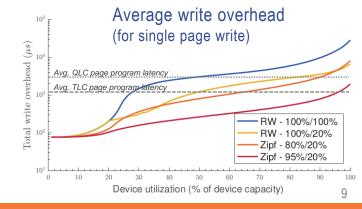
#### Modeling experiment (see [1] for details):

- Workloads:
  - Zipfian writes with skew factors 95/20 and 80/20
  - Uniform random writes to whole or partial data set
- Hybrid controller with full write heat separation
  - Controller determines optimal SLC/QLC ratio for given utilization
  - Controller determines optimal size of hot dataset to keep in SLC
- Results:
  - Significant improvements in both, endurance and write performance for skewed workloads
  - Skewed workloads outperform a TLC only controller even when device utilization is high

[1] R. Stoica, R. Pletka, N. Ioannou, N. Papandreou, S. Tomic, H. Pozidis, Understanding the design trade-offs of hybrid flash controllers, MASCOTS 2019









## Information encoding in NAND flash cells



Information encoding in NAND flash cells uses so called Gray coding schemes (reflected binary coding):

- The binary values are ordered in such a way that two successive values only differ in a single bit
- Gray coding guarantees that only one physical page is affected by a single bit flip.
- There are many possible Gray coding schemes which differ in the number of read voltage levels that must be tested upon reading a page of a particular page type
- Today, NAND flash devices only implement a single coding scheme that cannot be changed.
- Example Gray coding scheme for QLC with 4 page types PT<sub>a</sub>,...,PT<sub>d</sub>:

Page Type	E	L1	L2	L3	L4	L5	L6	L7	L8	L9	L10	L11	L12	L13	L14	L15	# Read voltage levels
PT <sub>a</sub> (LSB)	1	1	1	1	1	1	1	1	0	0	0	0	0	0	0	0	1 → fastest page
PT <sub>b</sub>	1	1	1	1	0	0	0	0	0	0	0	0	1	1	1	1	2
PT <sub>c</sub>	1	1	0	0	0	0	1	1	1	1	0	0	0	0	1	1	4
PT <sub>d</sub> (MSB)	1	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	8 → slowest page





## The potential of read heat separation



#### Read heat separation goals:

- Place frequently read data on faster pages
- Place data rarely read on slower pages

#### Achievable latency reductions depend on:

- The Gray coding scheme used
- Read skew of the workload
- Read and write workload mix

Maximum achievable average read latency reductions using {1, 2, 4, 8} Gray coding

(page types correspond to the read latencies of the QLC device X on slide 4)

Read Workload	Average Read Latency Reduction
Random	0.0%
Zipf 70/30	28.3%
Zipf 80/20	41.5%
Zipf 95/20	53.2%



Faster than average TLC latency!

[3] R. Pletka, N. Papandreou, R. Stoica, H. Pozidis, N. Ioannou, T. Fisher, A. Fry, K. Ingram, A. Walls, Improving NAND flash performance with read heat separation, MASCOTS 2020



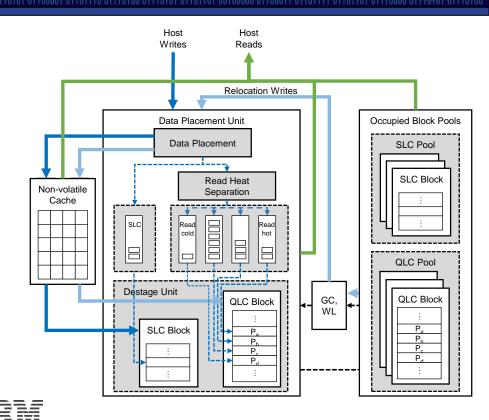


## Controller architecture for read heat separation



#### General concept:

- Read heat information is tracked on every host read operation
- Data placement unit performs read heat separation based on read heat information for all write operations
  - 1 SLC command queue
  - 4 QLC command queues (one for each page type)
- Preferably, there are as many instances of data placement unit as there are write heat streams in the controller



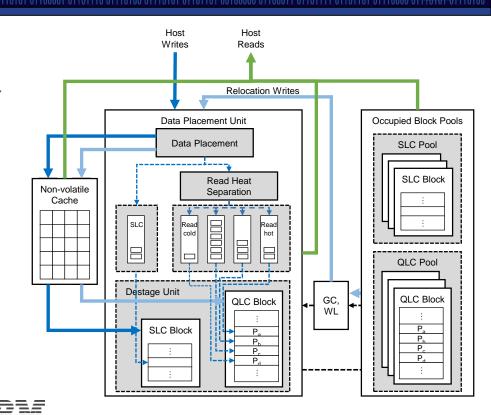


## Controller architecture for read heat separation



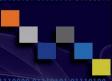
#### Write process:

- Store write data in non-volatile destaged buffer (MRAM, battery-backed DRAM, SLC, ...)
- Determine read heat (read heat information is tracked for each LBA)
- Perform read heat separation by placing the write request into the corresponding read heat queue
- Process writes by pulling from preferred readheat queue. When preferred read-heat queue is empty, pull write request from the next bestmatching non-empty read-heat queue.



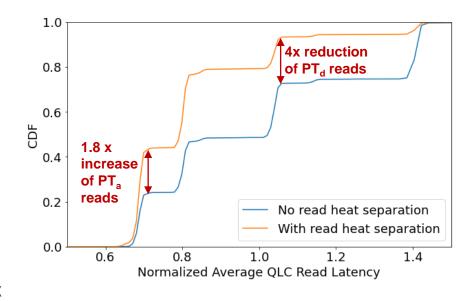


### Measurements from real SSDs



#### Read heat separation

- Experiment:
  - Preconditioned device with 80% of logical capacity used
  - 2 read workloads:
    - ❖ 95% of reads to only 5% of the written LBA space
    - ❖ 5% reads to 95% of the written LBA space
  - Uniform random write workload
- Results:
  - Reads from fastest PT<sub>a</sub> pages increases by 1.8x
  - Reads from slowest PT<sub>d</sub> pages reduced by 4x



17.1% in average read latency reduction achieved



## Measurements from real SSDs



#### Workload:

Uniform random, high queue depth (constant IOPS)

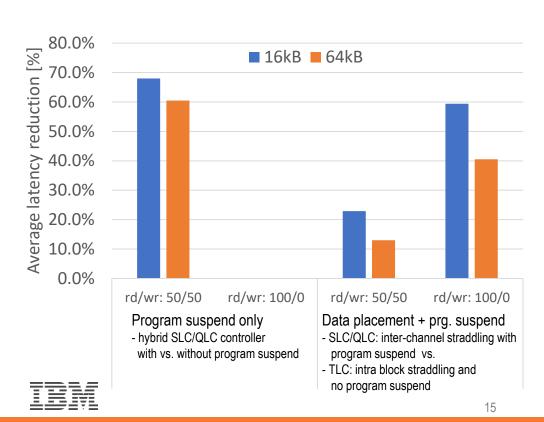
#### Measurements:

- Average read latency reductions
  - From program suspend
  - From optimized data placement
  - 3D TLC only vs SLC/QLC NAND flash controller

#### Findings:

- Write suspend reduces the average read latency by up to 68% in mixed read/write workloads
- A hybrid SLC/QLC controller with intelligent data placement and program suspend can significantly outperform a traditional TLC controller

Santa Clara, CA November 2020





## Conclusion



- Novel controller design approaches are essential to address the shortcomings of latest high-density 3D QLC NAND flash generations
- Key aspects to improve performance are
  - A dynamically resizable hybrid controller architecture
  - Data straddling on sub-page level
  - Workload dependent data placement using read and write heat separation
  - Continuous background block calibration
- Using these techniques, enterprise-level SSD controllers can be built using QLC flash that outperform previous NAND flash generations



## Thank You!



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